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Introduction

In pursuit of new devices and advanced materials, it is more and more desirable to combine or integrate different properties and functionalities within one single phase material. The renaissance of multiferroics in the last decade represents such trend.^{1,2} Multiferroics are of great importance for both fundamental science and the potential applications in new devices based on the mutual controls of magnetic and electric

$[NH_2NH_3][M(HCOO)_3]$ (M = Mn²⁺, Zn²⁺, Co²⁺ and Mg²⁺): structural phase transitions, prominent dielectric anomalies and negative thermal expansion, and magnetic ordering⁺

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We report here a new class of ammonium metal-formate frameworks of [NH₂NH₃][M(HCOO)₃] $(M = Mn^{2+}, Zn^{2+}, Co^{2+} and Mg^{2+})$ incorporating hydrazinium as the cationic template and component. The perovskite Mn and Zn members possess anionic 4¹²·6³ metal-formate frameworks with cubic cavities occupied by the $NH_2NH_3^+$ cations, while the Co and Mg members have chiral $4^{9.66}$ metal-formate frameworks, with chiral hexagonal channels accommodating $NH_2NH_3^+$ cations. On heating, the Mn and Zn members undergo phase transitions around 350 K. The structures change from low temperature (LT) polar phases in Pna21 to high temperature (HT) non-polar phases in Pnma, due to the thermally activated librational movement of the NH_2 end of the $NH_2NH_3^+$ in the cavity and significant framework regulation. The Co and Mg members in LT belong to non-polar $P2_12_12_1$, are probably antiferroelectric, and they show phase transitions at 380 K (Co) and 348 K (Mg), and the structures change to polar HT phases in P63, triggered by the order-disorder transition of the cation from one unique orientation in LT to three of trigonally-disorder state in HT. Accompanying the phase transitions, which are ferro- to para-electric for Mn and Zn members while antiferro- to ferro-electric for Co and Mg, prominent anisotropic thermal expansions including negative ones, and dielectric anomalies, are observed. The spontaneous polarization values are estimated at 3.58 (Mn, 110 K), 3.48 (Zn, 110 K), 2.61 (Co, 405 K) and 3.44 (Mg, 400 K) μC cm⁻², respectively, based on the positive and negative charge separations in the polar structures. The structureproperty relevance is established based on the order-disorder transitions of $NH_2NH_3^+$ and the conformity and adaptability of the metal-formate frameworks to match such order-disorder alternations. The Mn and Co members show spin-canted antiferromagnetic long-range-ordering, with Néel temperatures of 7.9 K and 13.9 K, respectively. Therefore, the two members show coexistence of electric and magnetic orderings in the low temperature region, and they are possible molecule-based multiferroics.

> fields. The materials of metal-organic frameworks, MOFs, have received considerable attention for multi-functional materials.³⁻⁷ These materials, by combining inorganic and organic components, can not only possess new and interesting properties or functionalities,⁴ originating from their organicinorganic hybrid character,3 but also afford possible coexistence and/or synergism of multiple functionalities within one material. Indeed, multi-functionalities such as conductivity and magnetism,⁵ magnetic and optical properties,⁶ porosity and magnetism,⁷ have been all realized in MOF materials, by incorporating suitable inorganic and organic building blocks and structural features within MOFs. More recently, several MOFs showing coexistence of magnetic and electric orderings or multiferroics have emerged,8 however, these MOF-/ molecule-based multiferroics are still very limited compared to the much more well developed pure inorganic ones.^{1,2} On the other hand, it has been now realized that MOFs themselves

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could display a rich variety of physical properties and critical phenomena or phase transitions.9 In addition to the magnetic¹⁰ and electric^{11,12} transitions, the unusual mechanical properties of negative thermal expansion (NTE)¹³⁻¹⁶ and the related framework dynamics,¹⁷ negative linear compressibility (NLC),¹⁸ pressure or temperature induced amorphization¹⁹ and so on have aroused great interest from both a fundamental and a practical point of view, as have those for conventional materials such as oxides.9 These properties are all very closely linked to the structural modifications and/or structural transitions, therefore are possibly also linked one to another. The close link between anisotropic thermal expansion (ATE), including NTE, and the ferro- to para-electric transition is well known for classical ferroelectrics such as BaTiO₃ (BTO) and potassium dihydrogen phosphate (KDP) in which the underlying mechanism is order-disorder transitions of cationic components.20

Along these lines, we and other authors have studied the ammonium metal-formate frameworks (hereafter abbr. AMFFs) systematically.²¹ AMFFs are promising MOFs for magnetic and/or electric orderings and phase transitions because of the following observations. (i) The formate HCOO⁻, the smallest and simplest carboxylate, can adopt various bridging modes such as syn-syn, anti-anti, syn-syn/anti, all short bridges, to link metal ions, and it has small stereo effects. These are all beneficial properties for the formation of MOFs, and for the significant magnetic coupling between magnetic metal sites. (ii) Formate is a good hydrogen-bonding acceptor (hereafter HB = hydrogen-bonding/bond), and the ammonium ions are good HB donors. The combination of such components could produce HB systems required for ferro-/antiferro-electric properties in molecule-based materials, such as those in traditional KDP and TGS,²⁰ and recently organic ones.²² (iii) The metal-formate frameworks have shown malleability and adaptability to conform to the ammonium ions employed, not only the different framework structure types depending on the size, shape, charge etc. of the ammonium ions, but also the framework flexibility and modulation to the order/disorder status of the cations. For AMFFs, many interestdevelopments have been recently ing results and reported.^{21,22-34} The [NH₄][M(HCOO)₃]²³ and [(CH₃)₂NH₂]- $[M(HCOO)_3]^{24-26}$ series (M = 3d magnetic metal), known as MOFbased multiferroics, display coexistence or synergism of magnetic and electric orderings. Giant dielectric anomalies and relaxor behaviors have been observed for [(CH₂)₃NH₂]-[M(HCOO)₃].²⁷ In several lanthanide metal systems, magnetic relaxation behaviors and structural transitions have been observed.²⁸ [C(NH₂)₃][Cu/Cr(HCOO)₃] have been suggested by DFT calculations to show possible magnetoelectric effect, but this is still awaiting experimental confirmation.²⁹ NTE and NLC have been observed for [NH₄][M(HCOO)₃]²³ and [CH₃NH₃]-[Mn(HCOO)₃].^{24a} Para- to antiferro-electric transitions of unusual structural alternations together with Néel N-type ferrimagnetism have been observed in mixed-valence [(CH₃)₂NH₂]-[Fe^{III}Fe^{II}(HCOO)₆].³⁰ It has been noted that the order-disorder transitions of ammonium cations could occur in most of these

AMFFs,²²⁻³⁴ as observed in many other systems including ammonium components.³⁵⁻³⁸

To build upon these interesting results and to continue our studies^{21,23-25,27,28,29a,33,34} on AMFFs, in this work we use the hydrazinium, NH₂NH₃⁺, as the cationic component and template to construct a new AMFF class of [NH₂NH₃][M(HCOO)₃], in which the four compounds are named as 1Mn, 2Zn, 3Co and 4Mg for M = Mn²⁺, Zn²⁺, Co²⁺ and Mg²⁺, respectively. The $\mathrm{NH_2NH_3}^+$ has an intermediate size, larger than $\mathrm{NH_4}^+$ and $\mathrm{HONH_3}^+$ ions^{23,33} but smaller than $\mathrm{CH_3NH_3}^+$ and other larger mono-ammonium ions,^{24-27,29-32} and it is a good HB donor and possible acceptor. The middle size of hydrazinium resulted in two typical AMFF structures within the series, one is the perovskites (1Mn and 2Zn) and the other the chiral frameworks (3Co and 4Mg). The materials all displayed interesting structural phase transitions with critical temperatures $(T_{\rm C} \text{ values})$ close to or above 350 K, comparable to inorganic BTO, accompanied by significant dielectric anomalies and ATE/NTE due to the order-disorder transitions of hydrazinium and the framework modulations. The materials were characterized by thermal analyses, variable temperature (VT) single crystal X-ray diffraction (SXRD) and powder X-ray diffraction (PXRD), and dielectric measurements. The magnetic 1Mn and 3Co showed long-range-ordering (LRO) of spin-canted antiferromagnetism (AF) in the low temperature region.

Experimental section

Synthesis

All chemicals were commercially available, reagent grade, and used without further purification. Cautionary note: perchlorate compounds are potentially explosive. They should be prepared in small quantities and handled with care.

The four compounds were synthesized by mild solution methods. Typically, 1Mn was prepared as follows. 5.0 ml of methanol solution containing formic acid 3.94 g (80 mmol) and an aqueous solution of 85% hydrazine 0.35 g (6.0 mmol) were mixed with 5.0 ml of methanol solution containing Mn- $(ClO_4)_2 \cdot 6H_2O$ 0.36 g (1.0 mmol). The mixed solution was kept undisturbed. After two days, the block-shaped colorless crystals of X-ray quality were collected, washed with ethanol and air-dried. The yield is 86% based on Mn(ClO₄)₂·6H₂O. 2Zn, 3Co and 4Mg were obtained similarly with yields of 80%, 96% and 90% for 2Zn, 3Co and 4Mg, respectively. Anal. (%) 1Mn, calcd for C₃H₈MnN₂O₆: C, 16.15; H, 3.61; N, 12.56; found: C, 16.15; H, 3.52; N, 12.53; 2Zn, calcd for C₃H₈ZnN₂O₆: C, 15.43; H, 3.45; N, 12.00; found: C, 15.48; H, 3.34; N, 11.89; 3Co, calcd for C₃H₈CoN₂O₆: C, 15.87; H, 3.55; N, 12.34; found: C, 15.99; H, 3.51; N, 12.21; 4Mg, calcd for C3H8MgN2O6: C, 18.73; H, 4.19; N, 14.56; found: C, 18.68; H, 4.16; N, 14.61. The crystals of 1Mn and 2Zn are nearly rectangular blocks or thick plates, while the crystals of 3Co and 4Mg are hexagonal blocks or pyramids (Fig. S1[†]).

X-ray crystallography and physical measurements

The SXRD intensity data for the single crystals of the four compounds at low temperatures (LT) were collected on a Nonius Kappa CCD diffractometer (CCD-1),³⁹ and data at high temperatures (HT) on an Agilent Technology SuperNova Dual Atlas CCD diffractometer (CCD-2),40 using monochromated Mo Ka radiation ($\lambda = 0.71073$ Å) and equipped temperature control systems. Crystals showed reversible phase transitions and all kept good crystallinity, though single crystals of 3Co and 4Mg became twinned from HT back to LT. All structures were solved by direct method and refined by full-matrix leastsquares on F² using SHELX program.⁴¹ The H atoms were located from the difference Fourier synthesis, but constrained according to the ideal geometries in refinements. For 3Co and 4Mg, the HT structures were solved in space groups $P6_3$ and $P6_322$. However, the structures refined in $P6_3$ resulted in significantly lower R factors (for 3Co, $R_1 = 0.016$ in $P6_3$ while 0.021 in P6₃22) and better models for the trigonally disordered hydrazinium with rational molecular geometry. The crystallographic data are briefly summarized in Table 1 while the details are reported in Table S1,† and the selected molecular geometries are listed in Table S2[†] (1Mn and 2Zn) and Table S3† (3Co and 4Mg). CCDC-958452 to 958467 contain the supplementary crystallographic data for this paper.

PXRD data were collected in the range of $5^{\circ} < 2\theta < 60^{\circ}$ at room temperature (RT) for the bulk samples and the pressed tablet samples on a Rigaku Dmax 2000 diffractometer, and VT PXRD patterns for the pressed tablet samples were collected on CCD-2, using Cu K α radiation.

Elemental analysis of C/H/N was performed on an Elementar Vario MICRO CUBE analyzer. FTIR spectra in the range of 4000 to 600 cm⁻¹ were recorded for pure samples on a NICOLET iN10 MX spectrometer. Thermal analyses were performed on a TA SDT Q600 simultaneous DSC-TGA instrument at the rate of 5 °C min⁻¹ in air flow. The DSC measurements were performed on a TA Q100 DSC analyzer at the rate of 5 °C min⁻¹ in N₂ flow and cycled two or three times.

The temperature-dependent ac (alternate current) dielectric permittivity measurements were carried out on a TH2828 Precision LCR meter under 20 frequencies from 100 Hz to 1 MHz and an applied voltage of 1.0 V, at a temperature sweeping rate of ca. 1 K min⁻¹ in dried N₂ flow. Samples were ground and pressed into tablets under a pressure of ca. 2 GPa. The phase purity of the pressed tablets and the absence of pressureinduced phase transitions were confirmed by PXRD (Fig. S2[†]). The capacitors were made by painting the two faces of the tablet pieces with silver conducting paste and copper or golden wires as the electrodes. These capacitors were kept vacuumdried over silica gel for more than two weeks and finally coated by a very thin layer of AB glue or vaseline before the dielectric measurements, in order to avoid the influence of moisture. The area and thickness of the capacitors were measured under a microscope with a Phenix CCD eye and the software.

Magnetic measurements for **1Mn** and **3Co** were performed on a Quantum Design MPMSXL5 SQUID system with polycrystalline samples tightly packed and sealed in a capsule. Diamagnetic corrections were estimated using Pascal constants $(-91 \times 10^{-6} \text{ and } -89 \times 10^{-6} \text{ cm}^3 \text{ mol}^{-1}$ for **1Mn** and **3Co**, respectively)⁴² and background correction by experimental measurement on sample holders.

Results and discussion

Synthesis, IR spectra, thermal properties, and structural phase transitions

The four AMFF materials were prepared under ambient conditions by employing suitable metal perchlorate salts, hydrazine (85% aqueous solution) and formic acid in methanol (see above). This mild solution chemistry method has proved to be very successful, general, convenient and performed easily in the preparation of various AMFFs in the last few years by us,^{21,23,24,27-29,33,34} though sometimes solvothermal methods were employed.^{25,26,30,32} The PXRD patterns (Fig. S2[†]) confirmed the phase purity of the products, so the small water component of the commercial aqueous hydrazine (85%) did not produce impurities of metal-formate dihydrate in the products, as frequently encountered.²¹ Similar observations were reported for the preparation of the mixed metal perovskites [CH₃NH₃][Mn_xZn_{1-x}(HCOO)₃],^{24b} niccolite [CH₃NH₂CH₂CH₂NH₂CH₃][Zn₂(HCOO)₆],^{34b} and the perovskite series of [C(NH₂)₃][M(HCOO)₃].^{29a} Another interesting observation for the present series is that 1Mn and 2Zn possess the most popular perovskite AMFF structures among several [AmineH][M(HCOO)3] series for mono ammonium ions^{24-27,29,31,32} where AmineH⁺ = CH₃NH₃⁺, (CH₃)₂NH₂⁺, $CH_3CH_2NH_3^+$, $(CH_2)_3NH_2^+$, $C(NH_2)_3^+$ and $(NH_2)_2CH^+$, while 3Co and 4Mg belong to the chiral structures of the type [NH₄]- $[M(HCOO)_3]^{23}$ and the recently reported $[HONH_3]$ - $[M(HCOO)_3]^{33}$ series. Given the fact that the four compounds have the same constituents except the different metal ions, and usually within one AMFF series the Mn, Fe, Co, Ni, Zn and Mg members are isostructural,²¹ this observation is quite unexpected. For each metal ion we could expect the existence of two phases or polymorphs. Indeed, we have found that for the Fe member the product is a mixture of two such phases.⁴³ We are still trying to obtain the two Fe phases in pure form so that they will be reported in the future, as well as to prepare the perovskite phases of 3Co and 4Mg and the chiral phases of 1Mn and 2Zn. Finally, attempts to prepare the Ni and Cu members within this series were not successful, probably due to the very low solubility of the Ni member²¹ and the easy reduction of Cu^{2+} by hydrazine.

The IR spectra of the four compounds are quite similar but still show some slight differences (Fig. S3[†]), given the fact that the structures belong to two types. The IR absorption bands and their assignments are given in Table S4,[†] and they are characteristic of $\rm NH_2NH_3^+$ and $\rm HCOO^-.^{33,44}$

The combined TGA-DSC runs up to 800 °C are shown in Fig. S4.† These materials basically showed two weight loss procedures on their TGA traces. The first endothermic one

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1Mn , formula = $C_3H_8MnN_2O_6$, f	w = 223.05			
<i>T</i> (K)	110	200	290	400
Crystal system	Orthorhombic	Orthorhombic	Orthorhombic	Orthorhombic
Space group	$Pna2_1$	$Pna2_1$	$Pna2_1$	Pnma
a (Å)	8.9319(3)	8.9503(3)	8.9448(3)	8.8505(3)
b (Å)	7.8190(2)	7.8214(2)	7.8403(3)	11.8785(4)
c (Å)	11.6928(5)	11.7189(5)	11.7669(5)	7.9240(3)
x (°)	90	90	90	90
3 (0)	90	90	90	90
(°)	90	90	90	90
$V(Å^3)$	816.61(5)	820.37(5)	825.21(5)	833.06(5)
$Z, D_{\rm c} ({\rm g \ cm^{-3}})$	4, 1.814	4, 1.806	4, 1.795	4, 1.778
$\mu (Mo K_{\alpha}) (mm^{-1}), F(000)$	1.613, 452	1.606, 452	1.597, 452	1.581, 452
No. total/uniq./obs. reflns.	15 236/2093/1540	15 362/2101/1439	15 111/2113/1378	12 844/1077/87
$R_1, wR_2 \text{ (for } I \ge 2\sigma(I)\text{)}$	0.0248, 0.0435	0.0243, 0.0408	0.0259, 0.0426	0.0297, 0.0779
GOF	0.912	0.885	0.885	1.226
		0.885	0.885	1.220
$2\mathbf{Zn}, \text{ formula} = C_3H_8ZnN_2O_6, \text{ fw}$	= 233.48			
T(K)	110 Orthorhomhia	200 Orthorhombia	290 Orthorhombio	375 Orthorhombio
Crystal system	Orthorhombic	Orthorhombic	Orthorhombic	Orthorhombic
Space group	$Pna2_1$	$Pna2_1$	$Pna2_1$	Pnma
a (Å)	8.6640(3)	8.6806(3)	8.6748(3)	8.5958(3)
b (Å)	7.7157(2)	7.7235(3)	7.7488(3)	11.6442(5)
c (Å)	11.4824(4)	11.5056(3)	11.5478(4)	7.8468(3)
α (°)	90	90	90	90
β (°)	90	90	90	90
/ (°)	90	90	90	90
$V(\dot{A}^3)$	767.58(4)	771.39(4)	776.23(5)	785.40(5)
$Z, D_{\rm c} ({\rm g \ cm^{-3}})$	4, 2.020	4, 2.010	4, 1.998	4, 1.975
$u (Mo K_{\alpha}) (mm^{-1}), F(000)$	3.196, 472	3.181, 472	3.161, 472	3.124, 472
No. total/uniq./obs. reflns.	14 003/1944/1427	14 258/1965/1369	14 396/1988/1329	11 343/1024/75
$R_1, wR_2 \text{ (for } I \ge 2\sigma(I)\text{)}$	0.0230, 0.0426	0.0227, 0.0402	0.0233, 0.0395	0.0294, 0.0727
GOF	0.931	0.942	0.892	1.154
3Co. formula = $C_3H_8CoN_2O_6$, fw	= 227.04			
3Co , formula = $C_3H_8CoN_2O_6$, fw		200	200	405
T (K)	110	200 Orth ach am hia	290 Orthershershie	405
T (K) Crystal system	110 Orthorhombic	Orthorhombic	Orthorhombic	Hexagonal
T (K) Crystal system Space group	110 Orthorhombic $P2_12_12_1$	Orthorhombic $P2_12_12_1$	Orthorhombic $P2_12_12_1$	Hexagonal <i>P</i> 6 ₃
T (K) Crystal system Space group α (Å)	110 Orthorhombic $P2_{1}2_{1}2_{1}$ 7.9435(2)	Orthorhombic $P2_12_12_1$ 7.9415(2)	Orthorhombic $P2_12_12_1$ 7.9341(3)	Hexagonal <i>P</i> 6 ₃ 7.9157(3)
T (K) Crystal system Space group a (Å) b (Å)	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4)	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5)	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7)	Hexagonal <i>P</i> 6 ₃ 7.9157(3) 7.9157(3)
$T (K)$ Crystal system Space group $a (\mathring{A})$ $b (\mathring{A})$ $c (\mathring{A})$	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2)	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2)	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3)	Hexagonal P6 ₃ 7.9157(3) 7.9157(3) 7.4836(3)
T (K) Crystal system Space group $a (\mathring{A})$ $b (\mathring{A})$ $c (\mathring{A})$ $a (^{\circ})$	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90	Hexagonal <i>P</i> 6 ₃ 7.9157(3) 7.9157(3) 7.4836(3) 90
T (K) Crystal system Space group $a (\mathring{A})$ $b (\mathring{A})$ $c (\mathring{A})$ $a (^{O})$ $\beta (^{O})$	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90	Hexagonal P6 ₃ 7.9157(3) 7.9157(3) 7.4836(3) 90 90
T (K) Crystal system Space group $a (\hat{A})$ $b (\hat{A})$ $c (\hat{A})$ $\alpha (^{O})$ $\beta (^{O})$ $\ell (^{O})$	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90	Hexagonal <i>P</i> 6 ₃ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00
$T (K)$ Crystal system Space group $a (\hat{A})$ $b (\hat{A})$ $c (\hat{A})$ $\beta (\circ)$ $\beta (\circ)$ $V (\hat{A}^{3})$	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90	Hexagonal P6 ₃ 7.9157(3) 7.9157(3) 7.4836(3) 90 90
T (K) Crystal system Space group $a(\hat{A})$ $b(\hat{A})$ $c(\hat{A})$ $\alpha(^{O})$ $\beta(^{O})$ $\gamma(^{O})$ $V(\hat{A}^{3})$ Z, D_{c} (g cm ⁻³)	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90	Hexagonal P6 ₃ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00
T (K) Crystal system Space group $a(\hat{A})$ $b(\hat{A})$ $c(\hat{A})$ $\alpha(^{O})$ $\beta(^{O})$ $\gamma(^{O})$ $V(\hat{A}^{3})$ Z, D_{c} (g cm ⁻³)	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90 90 802.37(4)	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4)	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6)	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3)
T (K) Crystal system Space group a (Å) b (Å) c (Å) α (°) β (°) γ (°) V (Å ³) Z, D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), F(000)	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90 802.37(4) 4, 1.880 2.136, 460	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230
T (K) Crystal system Space group a (Å) b (Å) c (Å) α (°) β (°) γ (°) V (Å ³) Z, D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), F(000) No. total/uniq./obs. reflns.	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90 90 802.37(4) 4, 1.880 2.136, 460 16 158/2071/1771	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648
3Co, formula = $C_3H_8CoN_2O_6$, fw <i>T</i> (K) Crystal system Space group <i>a</i> (Å) <i>b</i> (Å) <i>c</i> (Å) α (°) β (°) γ (°) γ (°) V (Å ³) <i>Z</i> , D_c (g cm ⁻³) μ (Mo K_{α}) (mm ⁻¹), <i>F</i> (000) No. total/uniq./obs. reflns. R_1 , w R_2 (for $I \ge 2\sigma(I)$) GOF	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90 802.37(4) 4, 1.880 2.136, 460	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460	Hexagonal P6 ₃ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857
<i>T</i> (K) Crystal system Space group <i>a</i> (Å) <i>b</i> (Å) <i>c</i> (Å) α (°) β (°) γ (°) <i>V</i> (Å ³) <i>Z</i> , D_c (g cm ⁻³) μ (Mo K_{α}) (mm ⁻¹), <i>F</i> (000) No. total/uniq./obs. reflns. R_1 , w R_2 (for $I \ge 2\sigma(I)$)	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90 802.37(4) 4, 1.880 2.136, 460 16 158/2071/1771 0.0244, 0.0458 0.988	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.0422
T (K) Crystal system Space group a (Å) b (Å) c (Å) a (°) β (°) γ (°) V (Å ³) Z, D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), $F(000)$ No. total/uniq./obs. reflns. R_1 , wR_2 (for $I \ge 2\sigma(I)$) GOF 4Mg , formula = C ₃ H ₈ MgN ₂ O ₆ , fr	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90 802.37(4) 4, 1.880 2.136, 460 16 158/2071/1771 0.0244, 0.0458 0.988	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497	Hexagonal $P6_3$ 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042
T (K) Crystal system Space group a (Å) b (Å) c (Å) x (°) g (°) v (Å ³) Z , D_c (g cm ⁻³) ι (Mo K_{α}) (mm ⁻¹), F(000) No. total/uniq./obs. reflns. R_1 , w R_2 (for $I \ge 2\sigma(I)$) GOF tMg , formula = C ₃ H ₈ MgN ₂ O ₆ , fw T (K)	110 Orthorhombic $P2_12_12_1$ 7.9435(2) 13.8339(4) 7.3016(2) 90 90 90 802.37(4) 4, 1.880 2.136, 460 16 158/2071/1771 0.0244, 0.0458 0.988 v = 192.42	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955	Hexagonal P63 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118
T (K) Crystal system Space group a (Å) b (Å) c (Å) a (°) a (°) a (°) a (°) b (Å) z , D_c (g cm ⁻³) a (Mo K_{α}) (mm ⁻¹), F(000) No. total/uniq./obs. refIns. R ₁ , w R_2 (for $I \ge 2\sigma(I)$) GOF tMg , formula = C ₃ H ₈ MgN ₂ O ₆ , fw T (K) Crystal system	$\begin{array}{c} 110\\ Orthorhombic\\ P2_12_12_1\\ 7.9435(2)\\ 13.8339(4)\\ 7.3016(2)\\ 90\\ 90\\ 90\\ 90\\ 802.37(4)\\ 4, 1.880\\ 2.136, 460\\ 16\ 158/2071/1771\\ 0.0244, 0.0458\\ 0.988\\ w = 192.42\\ \hline 110\\ Orthorhombic\\ \end{array}$	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic	Orthorhombic P2 ₁ 2 ₁ 2 ₁ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic	Hexagonal P63 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400
T (K) Crystal system Space group a (Å) b (Å) z (Å) x (°) g (°) χ (Å) Z, D_c (g cm ⁻³) ι (Mo K_{α}) (mm ⁻¹), F(000) No. total/uniq./obs. refIns. R_1, wR_2 (for $I \ge 2\sigma(I)$) GOF IMg , formula = C ₃ H ₈ MgN ₂ O ₆ , fw T (K) Crystal system Space group	$110 \\ Orthorhombic \\ P2_12_12_1 \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ w = 192.42 \\ \hline 110 \\ Orthorhombic \\ P2_12_12_1 \\ 10 \\ Orthorhombic \\ P2_12_12_1 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ $	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200	Orthorhombic P2 ₁ 2 ₁ 2 ₁ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292	Hexagonal P63 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal
T (K) Crystal system Space group $a(\hat{A})$ $b(\hat{A})$ $a(\hat{A})$	$110 \\ Orthorhombic \\ P2_12_12_1 \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ w = 192.42 \\ \hline 110 \\ Orthorhombic \\ P2_12_12_1 \\ 7.8999(2) \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ 0 \\ $	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P2_12_12_1$ 7.8928(2)	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2)	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3)
T (K) Crystal system space group $a(\mathring{A})$ $b(\mathring{A})$ $a(\circ)$ $b(\mathring{A})$ $c(\mathring{A})$ $a(\circ)$ $c(\circ)$ $c(\circ)$ $c(\circ)$ $c(\circ)$ $c((\circ)$ $c((\circ))$	$\begin{array}{c} 110\\ Orthorhombic\\ P2_{1}2_{1}2_{1}\\ 7.9435(2)\\ 13.8339(4)\\ 7.3016(2)\\ 90\\ 90\\ 90\\ 90\\ 802.37(4)\\ 4, 1.880\\ 2.136, 460\\ 16\ 158/2071/1771\\ 0.0244, 0.0458\\ 0.988\\ \hline v = 192.42\\ \hline 110\\ Orthorhombic\\ P2_{1}2_{1}2_{1}\\ 7.8999(2)\\ 13.7505(4)\\ \end{array}$	$\begin{array}{c} \text{Orthorhombic} \\ P2_12_12_1 \\ 7.9415(2) \\ 13.8460(5) \\ 7.3103(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 803.83(4) \\ 4, 1.876 \\ 2.132, 460 \\ 16 313/2074/1711 \\ 0.0263, 0.0490 \\ 0.965 \\ \hline \end{array}$	Orthorhombic $P2_12_12_1$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P2_12_12_1$ 7.8888(2) 13.7799(4)	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.8798(3)
T (K) Crystal system Space group $a(\dot{A})$ $b(\dot{A})$ $c(\dot{A})$ $a(\circ)$ $b(\dot{A})$ $c(\dot{A})$ $a(\circ)$ $b(\dot{A})$ $c(\dot{A})$ $a(\circ)$ $b(\dot{A})$ $c(\dot{A})$	$\begin{array}{c} 110\\ Orthorhombic\\ P2_{1}2_{1}2_{1}\\ 7.9435(2)\\ 13.8339(4)\\ 7.3016(2)\\ 90\\ 90\\ 90\\ 90\\ 802.37(4)\\ 4, 1.880\\ 2.136, 460\\ 16\ 158/2071/1771\\ 0.0244, 0.0458\\ 0.988\\ \hline v = 192.42\\ \hline 110\\ Orthorhombic\\ P2_{1}2_{1}2_{1}\\ 7.8999(2)\\ 13.7505(4)\\ 7.3829(2)\\ \end{array}$	$\begin{array}{c} \text{Orthorhombic}\\ P2_12_12_1\\ 7.9415(2)\\ 13.8460(5)\\ 7.3103(2)\\ 90\\ 90\\ 90\\ 90\\ 90\\ 803.83(4)\\ 4, 1.876\\ 2.132, 460\\ 16313/2074/1711\\ 0.0263, 0.0490\\ 0.965\\ \end{array}$	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2)	$\begin{array}{c} \mbox{Hexagonal}\\ P6_3\\ 7.9157(3)\\ 7.9157(3)\\ 7.4836(3)\\ 90\\ 90\\ 120.00\\ 406.09(3)\\ 2, 1.857\\ 2.110, 230\\ 6226/672/648\\ 0.0157, 0.042\\ 1.118\\ \hline \\ 400\\ \mbox{Hexagonal}\\ P6_3\\ 7.8798(3)\\ 7.5682(4)\\ \end{array}$
T (K) Crystal system Space group a (Å) b (Å) c (Å) α (°) β (°) V (Å ³) Z, D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), F(000) No. total/uniq./obs. reflns. R_1 , w R_2 (for $I \ge 2\sigma(I)$) GOF 4Mg , formula = C ₃ H ₈ MgN ₂ O ₆ , fv T (K) Crystal system Space group a (Å) b (Å) c (Å) α (°)	$\begin{array}{c} 110\\ Orthorhombic\\ P2_{1}2_{1}2_{1}\\ 7.9435(2)\\ 13.8339(4)\\ 7.3016(2)\\ 90\\ 90\\ 90\\ 90\\ 802.37(4)\\ 4, 1.880\\ 2.136, 460\\ 16158/2071/1771\\ 0.0244, 0.0458\\ 0.988\\ \hline v = 192.42\\ \hline \begin{array}{c} 110\\ Orthorhombic\\ P2_{1}2_{1}2_{1}\\ 7.8999(2)\\ 13.7505(4)\\ 7.3829(2)\\ 90\\ \end{array}$	$\begin{array}{c} \text{Orthorhombic} \\ P2_12_12_1 \\ 7.9415(2) \\ 13.8460(5) \\ 7.3103(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 803.83(4) \\ 4, 1.876 \\ 2.132, 460 \\ 16 313/2074/1711 \\ 0.0263, 0.0490 \\ 0.965 \\ \end{array}$	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.8798(3) 7.5682(4) 90
T (K) Crystal system Space group a (Å) b (Å) c (Å) x (°) g (°) V (Å ³) Z , D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), $F(000)$ No. total/uniq./obs. reflns. R_1 , wR_2 (for $I \ge 2\sigma(I)$) GOF 4Mg , formula = C ₃ H ₈ MgN ₂ O ₆ , fv T (K) Crystal system Space group a (Å) b (Å) z (Å) z (Å) z (Å) z (Å)	$\begin{array}{c} 110 \\ \text{Orthorhombic} \\ P2_12_12_1 \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ \textbf{v} = 192.42 \\ \hline \begin{array}{c} 110 \\ \text{Orthorhombic} \\ P2_12_12_1 \\ 7.8999(2) \\ 13.7505(4) \\ 7.3829(2) \\ 90 \\ 90 \\ \end{array}$	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P2_12_12_1$ 7.8928(2) 13.7693(4) 7.4007(2) 90 90 90	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90 90	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.8798(3) 7.8798(3) 7.8798(2) 90 90
T (K) Crystal system Space group $a(\hat{A})$ $b(\hat{A})$ $c(\hat{A}$	$\begin{array}{c} 110 \\ Orthorhombic \\ P2_12_12_1 \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ \hline v = 192.42 \\ \hline \begin{array}{c} 110 \\ Orthorhombic \\ P2_12_12_1 \\ 7.8999(2) \\ 13.7505(4) \\ 7.3829(2) \\ 90 \\ 90 \\ 90 \\ \end{array}$	Orthorhombic $P_{2_12_12_1}$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P_{2_12_12_1}$ 7.8928(2) 13.7693(4) 7.4007(2) 90 90 90 90	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90 90 90	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.8798(3) 7.5682(4) 90 90 120.00
$T (\mathbf{K})$ Crystal system Space group $a (\dot{\mathbf{A}})$ $b (\dot{\mathbf{A}})$ $b (\dot{\mathbf{A}})$ $z (\dot{\mathbf{A}})$ $z (\dot{\mathbf{A}})$ $z (D_c (\mathbf{g} \text{ cm}^{-3})$ $\iota (Mo K_{\alpha}) (mm^{-1}), F(000)$ No. total/uniq./obs. refIns. $R_1, wR_2 (\text{for } I \ge 2\sigma(I))$ GOF IMg , formula = $C_3H_8MgN_2O_6$, fw $T (\mathbf{K})$ Crystal system Space group $a (\dot{\mathbf{A}})$ $b (\dot{\mathbf{A}})$ $z (\dot{\mathbf{A}})$ $z (\dot{\mathbf{A}})$ $z (\dot{\mathbf{A}})$	$\begin{array}{c} 110 \\ Orthorhombic \\ P2_12_12_1 \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ \hline v = 192.42 \\ \hline \begin{array}{c} 110 \\ Orthorhombic \\ P2_12_12_1 \\ 7.8999(2) \\ 13.7505(4) \\ 7.3829(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 801.99(4) \\ \end{array}$	Orthorhombic $P_{2_12_12_1}$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P_{2_12_12_1}$ 7.8928(2) 13.7693(4) 7.4007(2) 90 90 90 804.30(4)	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90 90 90 807.64(4)	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.8798(3) 7.5682(4) 90 90 120.00 406.96(3)
T (K) Crystal system Space group a (Å) b (Å) c (Å) a (°) g (°) f (°) f (°) f (°) f (°) f (M) f	$\begin{array}{c} 110 \\ \text{Orthorhombic} \\ P2_12_12_1 \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 9$	Orthorhombic $P_{2_12_12_1}$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P_{2_12_12_1}$ 7.8928(2) 13.7693(4) 7.4007(2) 90 90 90 804.30(4) 4, 1.589	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90 90 90 90 807.64(4) 4, 1.583	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.8798(3) 7.5682(4) 90 90 120.00 406.96(3) 2, 1.570
T (K) Crystal system Space group a (Å) b (Å) c (Å) a (°) g (°) ℓ (°) V (Å ³) Z, D_c (g cm ⁻³) ι (Mo K_{α}) (mm ⁻¹), <i>F</i> (000) No. total/uniq./obs. refIns. R_1, wR_2 (for $I \ge 2\sigma(I)$) GOF tMg , formula = C ₃ H ₈ MgN ₂ O ₆ , fw T (K) Crystal system Space group τ (Å) b (Å) z (Å) χ (°) g (°) ℓ (°) V (Å ³) Z, D_c (g cm ⁻³) ι (Mo K_{α}) (mm ⁻¹), <i>F</i> (000)	$\begin{array}{c} 110 \\ Orthorhombic \\ P2_{1}2_{1}2_{1} \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ \hline v = 192.42 \\ \hline \begin{array}{c} 110 \\ Orthorhombic \\ P2_{1}2_{1}2_{1} \\ 7.8999(2) \\ 13.7505(4) \\ 7.3829(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 801.99(4) \\ 4, 1.594 \\ 0.219, 400 \\ \end{array}$	Orthorhombic $P_{2_12_12_1}$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P_{2_12_12_1}$ 7.8928(2) 13.7693(4) 7.4007(2) 90 90 90 804.30(4) 4, 1.589 0.218, 400	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90 90 90 807.64(4) 4, 1.583 0.217, 400	Hexagonal P_{6_3} 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal P_{6_3} 7.8798(3) 7.8798(3) 7.5682(4) 90 90 120.00 406.96(3) 2, 1.570 0.216, 200
T (K) Crystal system Space group a (Å) b (Å) c (Å) a' (°) b' (°) V (Å ³) Z, D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), F(000) No. total/uniq./obs. refIns. R_1, wR_2 (for $I \ge 2\sigma(I)$) GOF 4Mg , formula = C ₃ H ₈ MgN ₂ O ₆ , fw T (K) Crystal system Space group a (Å) b' (Å) c (Å) a' (°) b' (Å) c (Å) a' (°) b' (Å) z (A) a' (°) b' (Å) z (A) z' (D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), F(000) No. total/uniq./obs. refIns.	$\begin{array}{c} 110 \\ Orthorhombic \\ P2_{1}2_{1}2_{1} \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ \hline v = 192.42 \\ \hline \begin{array}{c} 110 \\ Orthorhombic \\ P2_{1}2_{1}2_{1} \\ 7.8999(2) \\ 13.7505(4) \\ 7.3829(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 801.99(4) \\ 4, 1.594 \\ 0.219, 400 \\ 14 126/1993/1864 \\ \end{array}$	Orthorhombic $P2_12_12_1$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P2_12_12_1$ 7.8928(2) 13.7693(4) 7.4007(2) 90 90 804.30(4) 4, 1.589 0.218, 400 14 119/1993/1827	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90 90 90 90 807.64(4) 4, 1.583 0.217, 400 14 178/1996/1756	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.5682(4) 90 90 120.00 406.96(3) 2, 1.570 0.216, 200 6712/678/654
T (K) Crystal system Space group a (Å) b (Å) c (Å) a (°) β (°) γ (°) V (Å ³) Z, D_c (g cm ⁻³) u (Mo K_{α}) (mm ⁻¹), $F(000)$ No. total/uniq./obs. reflns. R_1 , wR_2 (for $I \ge 2\sigma(I)$) GOF	$\begin{array}{c} 110 \\ Orthorhombic \\ P2_{1}2_{1}2_{1} \\ 7.9435(2) \\ 13.8339(4) \\ 7.3016(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 90 \\ 802.37(4) \\ 4, 1.880 \\ 2.136, 460 \\ 16 158/2071/1771 \\ 0.0244, 0.0458 \\ 0.988 \\ \hline v = 192.42 \\ \hline \begin{array}{c} 110 \\ Orthorhombic \\ P2_{1}2_{1}2_{1} \\ 7.8999(2) \\ 13.7505(4) \\ 7.3829(2) \\ 90 \\ 90 \\ 90 \\ 90 \\ 801.99(4) \\ 4, 1.594 \\ 0.219, 400 \\ \end{array}$	Orthorhombic $P_{2_12_12_1}$ 7.9415(2) 13.8460(5) 7.3103(2) 90 90 90 90 803.83(4) 4, 1.876 2.132, 460 16 313/2074/1711 0.0263, 0.0490 0.965 200 Orthorhombic $P_{2_12_12_1}$ 7.8928(2) 13.7693(4) 7.4007(2) 90 90 90 804.30(4) 4, 1.589 0.218, 400	Orthorhombic $P_{2_12_12_1}$ 7.9341(3) 13.8697(7) 7.3361(3) 90 90 90 807.29(6) 4, 1.868 2.123, 460 14 202/2077/1607 0.0279, 0.0497 0.955 292 Orthorhombic $P_{2_12_12_1}$ 7.8888(2) 13.7799(4) 7.4295(2) 90 90 90 807.64(4) 4, 1.583 0.217, 400	Hexagonal $P6_3$ 7.9157(3) 7.9157(3) 7.4836(3) 90 90 120.00 406.09(3) 2, 1.857 2.110, 230 6226/672/648 0.0157, 0.042 1.118 400 Hexagonal $P6_3$ 7.8798(3) 7.5682(4) 90 90 120.00 406.96(3) 2, 1.570

Table 1 Summary of crystallographic data for 1Mn, 2Zn, 3Co and 4Mg

Table 2	Summary of phase trans	itions and thermal and	dielectric properties fo	or 1Mn, 2Zn, 3Co and 4Mg
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Thermal properties and phase transitions (up = heating, down = cooling, and av = averaged) $T_{\rm C}$ (K), by DSC peaks $357^{\rm up}$, $353^{\rm down}$ $350^{\rm up}$, $349^{\rm down}$ $382^{\rm up}$, $377^{\rm down}$ $349^{\rm up}$, $348^{\rm av}$ ΔH (kJ mol ⁻¹), by DSC 3.9 3.4 3.1 2.6 ΔS (J mol ⁻¹ K ⁻¹), N, by DSC, 10.8 , 3.7 9.7 , 3.2 8.2 , 2.7 7.5 , 2.5 $T_{\rm C}$ (K), by TGA-DSC $350^{\rm up}$ $352^{\rm up}$ $381^{\rm up}$ $350^{\rm up}$ $T_{\rm C}$ range (K), by VT PXRD $350^{-360^{\rm up}}$ $350^{-360^{\rm up}}$ $380^{-390^{\rm up}}$ $340^{-350^{\rm up}}$ $T_{\rm C}$ range (K), by VT PXRD $350^{-360^{\rm up}$ $350^{-360^{\rm up}}$ $380^{-390^{\rm up}}$ $340^{-350^{\rm up}}$ $T_{\rm c}$ range (K), by VT PXRD $350^{-360^{\rm up}$ 360^{-410} $440^{-350^{\rm up}}$ $340^{-350^{\rm up}}$ $340^{-350^{\rm up}}$ $T_{\rm um}$ a (K), and e' value at $353, 10.4^{-10^{-3}}$ $84^{-410^{-3}}$ $84^{-30^{-30^{\rm up}}$ $343^{-350^{\rm up}}$ $342, 12.2^{-10^{-3}}$ $375^{-390^{-30^{\rm up}}$ $343^{-350^{\rm up}}$ $343^{-350^{\rm up}}$ $343^{-350^{\rm up}}$ $343^{-350^{\rm up}}$ $343^{-350^{\rm up}}$ $344^{-35^{-10^{-3}}$ $340^{-35^$	Compound	1Mn	2Zn	3Co	4Mg
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	Thermal	properties and phase transit	ions (up = heating, down = co	ooling, and av = averaged)	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$T_{\rm C}$ (K), by DSC peaks	357 ^{up} , 353 ^{down}	350 ^{up} , 349 ^{down}	382 ^{up} , 377 ^{down}	349 ^{up} , 348 ^{down}
$\begin{array}{cccccccccccccccccccccccccccccccccccc$				380 ^{av}	348 ^{av}
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	ΔH (kJ mol ⁻¹), by DSC	3.9	3.4	3.1	2.6
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	ΔS (J mol ⁻¹ K ⁻¹), N, by DSC,	10.8, 3.7	9.7, 3.2	8.2, 2.7	7.5, 2.5
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$T_{\rm C}$ (K), by TGA-DSC	357 ^{up}	352 ^{up}	381 ^{up}	350 ^{up}
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$T_{\rm d}$ (K), by TGA-DSC	400	380	430	450
Dielectric properties (from ε' data at 1 MHz) $\varepsilon'_{290 \text{ K}}$ 7.1 8.4 8.4 8.1 T_{turn} ^a (K), and ε' value at 353, 10.4 342, 12.2 378, 12.6 336, 9.9 turning point in ε' 7 9 364peak, 28.0 362sh, 25.4 405sh, 32.1 343sh, 11.2 peak or shoulder point in ε' 7 90 340, 364, 415 353, 24.1 $T_{d\varepsilon'/dT} peak$ (K) at $d\varepsilon'/dT$ peak 362 357 390 340, 364, 415 C and T_0 (K) HT: 3.2×10^2 , 353 LT: 3.3×10^2 , 372 LT: 3.3×10^2 , 405 1: 3.4×10^3 , 508 Transition type, LT to HT Ferro to para Ferro to para Antiferro to ferro Antiferro to ferro	$T_{\rm C}$ range (K), by VT PXRD	350-360 ^{up}	350-360 ^{up}	380-390 ^{up}	340-350 ^{up}
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$T_{\rm d}$ (K), by VT PXRD	400	360	410	440
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		Dielectric pro	perties (from ε' data at 1 MHz	z)	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	ε' _{290 K}	7.1	8.4	8.4	8.1
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$T_{\rm turn}^{a}$ (K), and ε' value at	353, 10.4	342, 12.2	378, 12.6	336, 9.9
peak or shoulder point in ε' 375sh, 24.1 $T_{d\varepsilon'/dT peak}$ 362357390340, 364, 415 C and T_0 (K)HT: 3.2×10^2 , 353LT: 3.3×10^2 , 372LT: 3.3×10^2 , 405I: 3.4×10^3 , 508Transition type, LT to HTFerro to paraFerro to paraAntiferro to ferroAntiferro to ferro	turning point in ϵ'				
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		364peak, 28.0	362sh, 25.4	405sh, 32.1	343sh, 11.2
C and T_0 (K) HT: 3.2×10^2 , 353 LT: 3.3×10^2 , 372 LT: 3.3×10^2 , 405 I: 3.4×10^3 , 508 Transition type, LT to HT Ferro to para Ferro to para Antiferro to ferro					375sh, 24.1
LT: 1.4×10^2 , 368II: 5.4×10^2 , 393Transition type, LT to HTFerro to paraFerro to paraAntiferro to ferroAntiferro to ferro	$T_{d\varepsilon'/dT peak}$ (K) at $d\varepsilon'/dT$ peak				
Transition type, LT to HTFerro to paraFerro to paraAntiferro to ferroAntiferro to ferro	$C \text{ and } \overline{T}_0 (\mathbf{K})$		LT: 3.3×10^2 , 372	LT: 3.3×10^2 , 405	
		LT: 1.4×10^2 , 368			
$F_{\rm c}$ (eV) $\tau_{\rm c}$ (s) for relavation 1.03 1.45 x 10 ⁻¹⁷		Ferro to para	Ferro to para	Antiferro to ferro	
	$E_{\rm a}$ (eV), τ_0 (s), for relaxation				$1.03, 1.45 \times 10^{-17}$
Estimated $P_{\rm S}^{\ b} (\mu {\rm C} {\rm cm}^{-2})$ 3.58 3.48 2.61 3.44		3.58	3.48	2.61	3.44
Aizu notation mmmFmm2 mmmFmm2	Aizu notation	mmmFmm2	mmmFmm2		

^{*a*} The first turning points from room temperature in ε' vs. T plots. ^{*b*} Spontaneous polarization.

occurred around 130, 110, 160 and 180 °C (decomposition temperatures T_d = 400, 380, 430 and 450 K, Table 2) for 1Mn, 2Zn, 3Co and 4Mg, respectively, and the weight losses were 33.4 (1Mn), 33.3 (2Zn), 33.8 (3Co) and 40.5% (4Mg), corresponding to the departure of one NH2NH2·HCOOH per formula with calculated weight losses of 33.5 (1Mn), 33.4 (2Zn), 34.4 (3Co) and 40.6% (4Mg), respectively, although for 1Mn, 2Zn and 3Co this procedure might include two sub-steps. The energy acquirements were 120 kJ mol⁻¹. After the first decomposition, 1Mn and 3Co further decomposed around 300 °C with high exothermic peaks and energy releases of 540 (1Mn) and 690 (3Co) kJ mol⁻¹. 2Zn further decomposed in two steps, one weak endothermic (3 kJ mol⁻¹) around 400 °C and one strong exothermic (290 kJ mol⁻¹) around 580 °C. The pyrolysis of 4Mg occurred at ca. 420 °C with an energy release of 57 kJ mol⁻¹. The final residues were 35.7, 31.7, 33.8 and 20.8% for 1Mn, 2Zn, 3Co and 4Mg, respectively, in agreement with the calculated values of 35.4, 33.0, 34.9 and 20.9% based on Mn₂O₃, ZnO, CoO and MgO. The thermal stabilities of the present series are similar to other mono-ammonium metalformate series^{23–25,33} except for the most stable $[C(NH_2)_3]$ - $[M(HCOO)_3]$ structures.^{29a} It should be noted that the four materials showed small but perceivable endothermic peaks around 84, 79, 108 and 77 °C (357, 352, 381 and 350 K) for 1Mn, 2Zn, 3Co and 4Mg, respectively, before their first decomposition in the DSC plots (Fig. S4b,† inset), and these indicated the occurrence of phase transitions.

These phase transitions were further confirmed by the more accurate DSC measurements (Fig. 1, Fig. S5,† Table 2). In the DSC traces endo/exothermic peaks were clearly observed at 357/353 K (**1Mn**), 350/349 K (**2Zn**), 382/377 K (**3Co**) and 349/347 K (**4Mg**, the highest peak positions), respectively, on heating/cooling, showing thermal hysteresis of few Kelvin. The

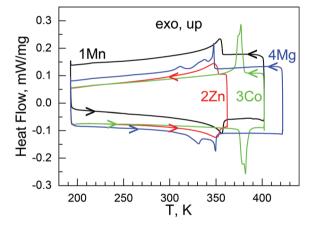


Fig. 1 The DSC traces for the four compounds, all first cycle.

 $T_{\rm C}$ values could be defined to be the averaged values, 355 K (1Mn), 350 K (2Zn), 380 K (3Co), and 348 K (4Mg). 1Mn and 2Zn displayed single, cycle-independent peaks with a somewhat extending tail on the low temperature side. 3Co possessed narrow and more prominent peaks, showing a shoulder in the first cycle. In the second cycle, the shoulder disappeared on heating but restored on the followed cooling. 4Mg behaved in a quite complicated manner, with two, even three thermic peaks in the range of 330 to 350 K, indicating a probably multi-step phase transition. The ΔH values (in kJ mol⁻¹) for the phase transitions were estimated at 3.9 ± 0.2 (1Mn), $3.4 \pm$ 0.1 (2Zn), 3.1 \pm 0.1 (3Co), 2.6 \pm 0.1 (4Mg), and the ΔS (ΔS = $\Delta H/T_{\rm C}$ ⁴⁵ values were estimated at 10.8 to 7.5 J mol⁻¹ K⁻¹ for the phase transitions. From the Boltzmann equation, $\Delta S =$ $R \ln(N)$, R being the gas constant and N the ratio of the numbers of respective distinguishable states of different phases,

N values of 3.7 to 2.5 could be calculated (Table 2). These values are roughly agreeable with 2 or 3 discrete states for the disordered $NH_2NH_3^+$ cation in the HT phases but 1 for the ordered $NH_2NH_3^+$ cation in the LT phases (see below). It is noted that the materials of the present series have high T_C values, all close to the typical ferroelectric oxide BTO,²⁰ comparing with the previously reported AMFF series showing structural phase transitions, $[(CH_3)_2NH_2][M(HCOO)_3]$,^{26,31} $[NH_4][M(HCOO)_3]^{23}$ and $[(CH_2)_3NH_2][M(HCOO)_3]$,²⁷ with T_C values below room temperature.

The VT PXRD patterns for the four compounds are shown in Fig. S6.[†] On heating, the phase transitions were evidenced by the changes, highlighted by stars in the patterns occurring around the individual $T_{\rm C}$ values, including the merging of some diffraction peaks, disappearance of some weak peaks, and relative intensity changes of some peaks, from LT to HT, corresponding to the elevation in structure symmetry. The experimental patterns matched the simulated ones based on the single crystal structures of different phases, confirming the phase transitions, and the T_C values determined by VT PXRD are within 350-360 K (1Mn and 2Zn), 380-390 K (3Co), and 340-350 K (4Mg) (Table 2). The VT PXRD patterns could also provide the thermal stability for the powders of the materials, up to the T_d values, ca. 410 K (1Mn), 360 K (2Zn), 410 K (3Co), and 440 K (4Mg). These data agree with the thermal analyses. It is worth mentioning that the powder samples of 2Zn to 3Co decomposed shortly after their phase transition, but the single crystals showed better thermal stability. For example, we have successfully collected intensity data for a single crystal of 2Zn at 375 K, 15 K higher than the T_d = 360 K observed for powder.

Crystal structures and the relevant negative thermal expansion

The crystal structures of the ordered LT phase and the disordered HT phase were determined (Table 1, Table S1†) by SXRD. **1Mn** and **2Zn** are perovskites (Fig. 2), as are those of [AmineH][M(HCOO)₃] for mono-ammonium ions with 2–4 non-H atoms,^{24–27,29,31,32} while **3Co** and **4Mg** possess the chiral metal–formate networks (Fig. 3) as do those of [NH₄]-[M(HCOO)₃],²³ K[M(HCOO)₃]⁴⁶ and the very recently reported [HONH₃][M(HCOO)₃] series.³³ They all displayed significant ATE/NTE accompanying the phase transition.

The isostructural perovskites **1Mn** and **2Zn** possess the anionic NaCl-frameworks of $[M(HCOO)_3^-]$ with the cubic cavities occupied by the NH₂NH₃⁺ cations (Fig. 2). Their LT phases belong to the polar orthorhombic space group *Pna2*₁. In the structures, each octahedral metal ion connects to six neighboring metal ions in an octahedral spatial arrangement, through six *anti–anti* formates, thus forming a metal-formate framework with a topology of $4^{12} \cdot 6^3$ (Fig. 2a and 2b). At RT (Table S2†), the M–O distances are 2.178(2)–2.196(2) Å for **1Mn**, and 2.099(2)–2.115(2) Å for **2Zn**, respectively, and the *cis*- O–M–O angles are 86.37(7)–94.43(9)°, and the *trans*-O–M–O angles are 176.10(8)–179.08(8)°. The framework grid or cavity has M–OCHO–M edges of 5.908–5.951 and 5.791–5.817 Å for **1Mn** and **2Zn**, respectively. These data are comparable with other known perovskite AMFFs,^{24–27,29,31}

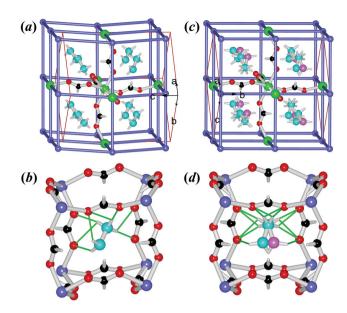


Fig. 2 The structure of **1Mn**: (a) and (b) at 290 K, (c) and (d) at 400 K. The frameworks (a and c) are in topological views, with one Mn connecting to its six neighbors by *anti–anti* formates, showing a octahedral spatial arrangement (large green Mn), and the details about the cavities and the $NH_2NH_3^+$ cations are shown in (b) and (d), with the thin green bonds representing the $N-H\cdots$ O HBs. Color scheme: Mn violet-blue/green, C black, H white, O red, N cyan/pink, and violet-blue sticks for $HCOO^-$ in (a) and (c).

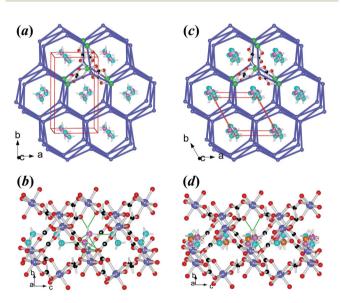


Fig. 3 The structure of **3Co**: (a) and (b) at 290 K, (c) and (d) at 405 K. The frameworks (a and c) are in topological views, with one Co connecting to its six neighbors by *anti–anti* formats, forming a centered trigonal prism (large green Co), and the details about the framework channels and the $NH_2NH_3^+$ cations are shown in (b) and (d), with the thin green bonds representing the $N-H\cdots O$ HBs. Color scheme: Co violet-blue/green, C black, H white, O red, N cyan/pink/orange, and violet-blue sticks for $HCOO^-$ in (a) and (c).

the decrease in the lattice dimensions and interatomic distances of M–O and M···M from **1Mn** to **2Zn** is in good agreement with the metal ionic radii.⁴⁷ The grid is somewhat

slanted, with the M-OCHO-M grid edges running along the c axis and the two diagonal directions of the ab plane. The cavity volumes are 44.4 (1Mn) and 40.1 (2Zn) Å³, calculated by PLATON (Fig. S7[†]).⁴⁸ These allow accommodation of the $NH_2NH_3^+$ cation with its vdW volume of 44 Å³ estimated by PCModel 9.1.⁴⁹ In the cavity, the NH₂NH₃⁺ cation has its long axis nearly lying on the longest body-diagonal of the cavity, and forms several N-H--O HBs to the anionic framework. Each N-H donor of the NH₃⁺ site of the cation forms one short (strong) and one long (weak) N-H--O HBs with the two O atoms from one formate, and the HB geometries are: for 1Mn, N···O distances 2.876(3)-2.926(4)/2.990(4)-3.110(3) Å, N-H···O angles 164.9-173.4/114.5-121.7°; for 2Zn, 2.878(4)-2.944(4)/ 2.970(4)-3.088(4) Å and 165.3-171.0/117.4-122.5°. Instead, each N-H donor of the NH2 site forms only one long, weak N-H····O_{HCOO} HB with N···O distances 3.034(4)-3.125(4) Å and N-H···O_{HCOO} angles 133.0–139.8°. Therefore, the neutral NH₂ site is loosely bonded comparing to the positive NH3⁺ site. The NH₂ end is also inclined to one side of the cavity, leaving the other side empty but available for forming alternative HBs. This asymmetry is very different from the mirror symmetric HBs and cation-cavity relationship in the very closely related [CH₃NH₃][M(HCOO)₃] perovskites²⁴ showing no phase transitions above 180 K. The loosely bonded NH₂ end and its asymmetric environment provide the possibility of movement at this end upon warming, as observed in the HT phases. In the framework the metal arrays along the *c* direction are slightly wavy, and all $NH_2NH_3^+$ cations have their NH_3^+ sites aslant towards the -c direction. These are compatible with the polar space group $Pna2_1$ and the lack of mirror in the *c* direction. On cooling down to 110 K the LT structures remain unchanged, with small decreases in cell dimensions and bond distances (Fig. S8a,[†] Table S2[†]). Therefore the LT structures are polar, and the polarization should be along the *c* axis. Indeed, if the planes of the metal atoms, perpendicular to the c axis, are considered as the average, symmetric planes for the distribution of the negative charges of the framework, all NH₂NH₃⁺ cations have their positive NH₃⁺ ends showing unequal out-of-plane distances from the two such planes on both sides of the NH_3^+ end, resulting in shifts, 0.457 Å for 1Mn and 0.417 Å for 2Zn, calculated from the 110 K structures, towards the -c direction with respect to the anionic framework. Assuming that the NH_3^+ ends are the positive point charges located at the N atoms,^{23a,b,50} these shifts generate dipoles, 4 per unit cell and parallel to each other, and the spontaneous polarization could be estimated at 3.58 (1Mn) and 3.48 (2Zn) μ C cm⁻² at 110 K (Table 2), which is typical for molecular ferroelectrics,^{11,20} along the -c direction.

The structures of the HT phases of **1Mn** at 400 K and **2Zn** at 375 K, all above the phase transition temperatures (Table 2), are centrosymmetric, in the space group *Pnma*, by addition of the mirror along the *b* direction of the HT lattices, *i.e.* the *c* direction of the LT lattices, as the relationship between the LT and HT conventional cells for both crystals is $a^{\text{HT}} \approx a^{\text{LT}}$, $b^{\text{HT}} \approx c^{\text{LT}}$ and $c^{\text{HT}} \approx -b^{\text{LT}}$. In the HT structures (Fig. 2c and 2d), while the metal-formate frameworks remain unchanged in their

topology, the differences in interatomic distances of M-O and M…M become smaller (Table S2[†]), and the wavy metal arrays in the LT structures are now straight. The most remarkable change in the structures is that the $NH_2NH_3^+$ cation shows two orientations in the HT phases, with its NH2 end splitting into two positions on the two sides of the mirror along the b direction. In fact this disorder, or the librational movement of the NH₂ end, introduces the mirror symmetry and thus the centrosymmetry for the HT phase. The NH₂NH₃⁺ cation now behaves as a pendulum, a property reminiscent of pendulum-type molecular ferroelectrics.³⁵ Its NH₃⁺ site is anchored by six N-H...O_{HCOO} HBs (N...O 2.928(3)-3.107(3) Å, N-H...O_{HCOO} 117-169°), but the NH2 end can vibrate. However, the $NH_2NH_3^+$ pendulum does not simply vibrate forward and back. At HT, the vibration locus of the NH₂ end across the mirror plane is, in fact, an arc (or a flat V-shape), as shown by the two mirror-symmetric elongated thermal ellipsoids, with the locus plane approximately perpendicular to the N-N bond (Fig. S9a[†]). The temperature evolution of the N ellipsoids from LT to HT also revealed that the gradually enhanced thermally agitated movements, perpendicular to the N-N bond for the NH_2 end, but approximately along the N–N bond for the NH_3^+ , finally led to the librational motion and the caused HB alternations. The two NH₂ sites are separated 0.74–0.75 Å, so the vibration amplitude of the NH2 end is 0.37 Å, which corresponds to the distance between NH₂ and the mirror plane. The two materials showed ATE behavior during the transition (Fig. S8a,^{\dagger} Table 3). The *b* and *c* axes (in LT cell setting) expand ca. 0.1 Å or 1% from 290 K to ca. 400 K, but the a axis contracts ca. 0.1 Å or 1%, resulting in NTE along the a direction. In fact the contraction of a axis might start from a lower temperature of 200 K. The coefficients of the thermal expansion (CTE, or α), negative or positive, are around 100×10^{-6} K^{-1} , estimated by currently available data, and these are classified as "colossal".^{15b} This behavior could be explained by the librational movement of $NH_2NH_3^+$ in the *c* direction with its long molecular axis lying approximately along the *a* direction, and the conformation adaptability of the metal-formate frameworks. The N-N distances are shortened ca. 0.03 Å from LT to HT, reflecting such librational motion. NTE has been observed in many classes of framework materials,13-16 such as oxides and zeolites¹⁴ (e.g., ZrW₂O₈ and AlPOs), cyanides¹⁵ (e.g., Zn-(CN)₂ and Ag₃[Co(CN)₆]), and MOFs¹⁶ (e.g., MOF-5 and HKUST-1), and the mechanism is thought to consist mainly of the transverse rigid unit modes or the transverse vibration of the linkages.¹³ The cavity volumes increase quite significantly, 52.8 (1Mn) and 45.2 (2Zn) Å³, compared to 44.4 (1Mn) and 40.1 (2Zn) Å³ of the LT phases at RT (Fig. S7†). The framework cavity becomes more regular (Fig. 2d vs. 2b). From these observations, we suggest that upon heating the expansion of the framework and the change in cavity shape and size and HBs allows first the vibration of the loosely HB-bonded NH2 end of the NH₂NH₃⁺ pendulum, then the contraction of the framework along the *a* direction but still an expansion along *b* and c, to fit such librational motion. This indicates a double potential well with a small energy barrier for the $NH_2NH_3^+$

Compound	1Mn			2Zn		
T range (K)	110-200	200-290	290-400	110-200	200-290	290-375
α _a	23	-7	-96	21	-7	-108
α_b	3	27	97	11	36	148
α _c	25	45	86	22	41	98
α_V	51	65	86	55	69	138
Compound	3Co			4Mg		
T range (K)	110-200	200-290	290-405	110-200	200-290	290-400
α_a	-3	-10	-20	-10	-6	-11
α_{bO}	10	19	-100	15	9	-89
$\alpha_{b\mathrm{H}}$	7	12	-81	9	5	-69
α_c	13	39	173	27	43	171
α_V	20	48	56	32	46	72

Table 3 The anisotropic coefficient of thermal expansion (α_b in 10⁻⁶ K⁻¹) for the four materials^a

^{*a*} The values were calculated through the equation $\alpha_l = \Delta l/(\Delta T \times l_{av})$ using the data at the two neighbor temperatures. For **1Mn** and **2Zn**, the cell settings of the HT phases were chosen as the same as the LT phases. For **3Co** and **4Mg**, *a* and *c* axes are the same for LT and HT phases, but for the *b* axis two settings, orthorhombic (*b*O) for LT and hexagonal (*b*H) for HT, were included. The accuracies were estimated at a few 10⁻⁶ K⁻¹ in most cases.

pendulum at HT. While in LT, this vibration is frozen. The fact that the LT phases have a polar space group $Pna2_1$ but the HT phases belong to the non-polar, centro-symmetric space group Pnma is of interest for ferroelectricity because such change, from Pnma to $Pna2_1$, implies the ferroelectric phase transitions on cooling, for **1Mn** and **2Zn**, with the Aizu notation mmFmm2.⁵¹ The higher N values of 3.7 (**1Mn**) and 3.2 (**2Zn**) by DSC studies indicate that the framework changes, from somewhat wavy one at LT to more regular straight one at HT, together with small twists in the orientation of formate bridges, should have the extra contribution to the N values. This is because the order-disorder transition of the cation, two discrete states in HT structures but one in LT, solely gives the ratio of states, N = 2.

3Co and 4Mg are isostructural (Table 1, S1c, S1d[†]), possessing a chiral metal-formate framework of 49.66 topology (Fig. 3), with hexagonal channels occupied by the NH_2NH_3 cations. As mentioned above, the occurrence of two different metal-formate frameworks within the present series is quite unusual. One possible reason is the size of NH₂NH₃⁺, with its vdW volume of 44 Å³, between the relevant ammonium ions,⁴⁹ 25 \AA^3 of NH₄⁺ and 38 \AA^3 of HONH₃⁺ for $4^9 \cdot 6^6$ frameworks, and 53 Å^3 of CH₃NH₃⁺ or above of other larger mono-ammonium ions for 4¹²·6³ ones. The LT structures of 3Co and 4Mg belong to chiral orthorhombic space group P212121, same as our recently published [HONH₃][M(HCOO)₃] series,³³ and possess quite similar lattice dimensions too (noting that in the present case the *c* axes are equivalent to the *b* axes in the $[HONH_3]$ - $[M(HCOO)_3]$ series). However, no phase transitions have been detected for the [HONH₃][M(HCOO)₃] series. Similarly, in 3Co and 4Mg, each octahedral metal node is connected to six neighbors via the anti-anti formate linkages, making up the centered trigonal prism within the frameworks (Fig. 3a). The MO₆ octahedron has M-O distances of 2.054(1)-2.122(2) Å, cis-O-M-O angles of 80.62(7)-96.01(7)°, and trans- O-M-O angles of 171.35(7)-176.14(5)° (Table S3,† at RT), similar to the reported data for other relevant Co or Mg AMFF

compounds.^{23,33} The frameworks possess slightly compressed hexagonal channels running along the c direction. In the channel (Fig. 3b) the NH₂NH₃⁺ cations are arranged side by side but aslant with respect to the c direction, showing a tilting angle of 65° between the molecular axes and the c direction, and the adjacent cations are oriented up and down. This is significantly different from the [HONH₃][M(HCOO)₃] series, in which the head to tail arranged HONH₃⁺ cations in the channel have tilting angles of 21°. The shorter c axes of 3Co and **4Mg** than the equivalent b axes of the $[HONH_3]$ -[M(HCOO)₃] series are compatible with this difference. Two N-H donors of the NH3⁺ end form four N-H…O HBs to the metalformate framework with N····O = 2.824(2)-2.945(2) Å, N-H···O angles 118.6–165.8°; and the left N-H donor points to the long electron pair of the NH₂ end of the adjacent cation, with N···N = 3.058–3.084 Å, and N–H…N angles of 172.9–176.4°. Whether this N-H...N interaction is a HB or a pseudo HB^{33,52} merits further investigation. The NH₂ end forms N-H…O HBs to the framework, with N····O = 2.946(2)-3.379(2) Å, and N-H···O angles of 101-146°, indicating weaker HB strengths compared to the NH_3^+ site. The strengths of cation-framework HBs involved in 3Co and 4Mg are weaker than those observed in the [HONH₃][M(HCOO)₃] series, in which a strong O-H…O HB between HONH₃⁺ and the framework probably prohibits the structural phase transition. In the framework the formatobridged M···M distances are 5.820-5.988 Å (Table S3[†]), larger than those of the perovskites (Table S2[†]) and the void spaces that the frameworks provide for each $NH_2NH_3^+$ are 49.7 (3Co) and 53.2 (4Mg) Å³. Surprisingly, these void spaces are larger than those found in 1Mn and 2Zn (Fig. S7[†]), and the framework is expanded. In fact, in the present series, the perovskite frameworks are denser than the chiral frameworks when considering the cell volumes, all per 4 formula of [NH2NH3]- $[M(HCOO)_3]$, and packing coefficients,⁵³ 807.3 (**3Co**) and 807.6 (4Mg) vs. 776.2 (2Zn) Å³ and 0.710 (3Co) and 0.705 (4Mg) vs. 0.745 (2Zn), considering that the three divalent metal ions have very close radii.⁴⁷ This is quite unexpected because in our

previous work we have observed that the chiral $4^9 \cdot 6^6$ frameworks should be denser than perovskite frameworks.^{21,33} The framework expansion of the chiral $4^9 \cdot 6^6$ frameworks vs. the perovskites within the series is due to the significant enlargement of the M-O-C angles of **3Co** and **4Mg**, 121.4(2)-131.9(1)°, compared with 1Mn and 2Zn, $118.2(2)-123.4(2)^{\circ}$, the change in these angles indicating again the breathing nature of the framework.^{24,54} The LT structures remained unchanged down to 110 K, showing a small decrease in b, c, V of the cell dimensions but a slight increase in *a*, thus NTE in the *a* direction (Table 3, Fig. S8b[†]), and a very slight decrease in the interatomic distances (Table S3^{\dagger}). The LT structures in $P2_12_12_1$ belong to the non-polar D_2 point group. However, the polarization properties merit to be discussed here. In fact, in one channel shown in Fig. 3b of the LT phase, the cations are tilting up and down, and their NH_3^+ ends shift slightly to +*c* and the NH_2 ends to -c with respect to the framework. This could result in a net, small dipole in the channel along the c direction, and the channels arranged along the *a* axis include the cations in the same tilting arrangement. Thus, these channels together with the cations forming a layer have the same polarization direction. However, the channels packing along the b direction contain $NH_2NH_3^+$ cations in different tilting directions, related by the 2₁ axis, thus resulting in anti-parallel arranged dipoles. Therefore, **3Co** and **4Mg** are antiferroelectrics²⁰ in LT.

After their phase transitions (Table 2), the two materials are still isostructural (Table 1, S1c, S1d,† Fig. 3c and 3d). The structures at 405 K for 3Co and 400 K for 4Mg revealed that the two materials underwent several remarkable changes from LT to HT in their symmetry, lattice, and orientations of the NH₂NH₃⁺ cations in the framework channel, though the framework topology remained unchanged. The space group changed from non-polar orthorhombic P212121 (LT) to polar hexagonal $P6_3$ (HT), and the HT unit cells doubly reduced compared to the LT ones, with a relationship of $a^{\text{HT}} \approx a^{\text{LT}}$, $b^{\text{HT}} \approx (b^{\text{LT}} - a^{\text{LT}})/2$ 2 and $c^{\text{HT}} \approx c^{\text{LT}}$, then $V^{\text{HT}} \approx V^{\text{LT}}/2$. In fact, if the primitive LT cell is added a C-center, the resultant C-centered lattice has a primitive cell with the following dimensions: for 3Co, a =7.9341, $b_{\rm H}$ = 7.9893, c = 7.3361 Å, $\alpha = \beta = 90^{\circ}$, $\gamma = 119.77^{\circ}$, and $V = 403.7 \text{ Å}^3$ and for **4Mg**, a = 7.8888, $b_{\text{H}} = 7.9391$, c = 7.4295 Å, $\alpha = \beta = 90^\circ$, $\gamma = 119.79^\circ$; and $V = 403.8 \text{ Å}^3$. These data are metrically very close to the hexagonal HT cells. Therefore, the HT cell is derived by the addition of C-centers upon the primitive orthorhombic LT cell, together with a/b shrinking but cexpanding (Fig. S8b,† Table 3). The α values are close to -100 \times $10^{-6}~{\rm K}^{-1}$ in the b direction, and 170 \times $10^{-6}~{\rm K}^{-1}$ for the c directions. These data are all quite large.¹¹ The frameworks become regularly hexagonal, and expand slightly, with fewer unique molecular geometries, by minor framework modulation. The void spaces for each $NH_2NH_3^+$ are 51.0 (3Co) and 54.5 (4Mg) $Å^3$, only 1.3 $Å^3$ larger than those in LT phases, quite different from the perovskites 1Mn and 2Zn showing more enlargements (Fig. S7[†]). The NH₂NH₃⁺ cation becomes trigonally disordered, with triplet orientations related by the 6_3 axis, and the molecular axis of $NH_2NH_3^+$ is more inclined to the c direction with a tilting angle of 52°, compatible with the ATE

in cell dimensions (a/b shrinking and c expanding) from LT to HT. After the phase transition the motion of the cation increased more significantly, as indicated by the more enlarged thermal ellipsoids, and the thermal ellipsoids of the O atoms of formate became more disk-like, indicating the coupling of the framework with the disordered state of $NH_2NH_3^+$ (Fig. S9b⁺). Again, it seems that the order-disorder transition of NH₂NH₃⁺ and the conformity or flexibility of the metal-formate frameworks to fit such transition contribute to the ATE. Such anisotropic changes in cell dimensions are a reversal of the behaviour observed for the [NH₄][M(HCOO)₃]^{23a,b} series, where a/b expanded and c shrank, with the same framework topology but different librational motion or disordered state of the cation. In fact, in [NH₄][M(HCOO)₃] the NH_4^+ cation oscillates along the *c* direction. Fewer and weaker HBs are observed for each orientation of NH₂NH₃⁺ as we countered 3 rational N-H···O HBs for the NH3⁺ end with longer N···O distances and probably only one for the NH2 end, and the N-H--N contacts between two adjacent cations are not favorable because the N-H groups are more or less oriented towards one another. Now in the polar HT structures the NH_3^+ ends of all cations shift toward +c, and the shifts are 0.331 and 0.437 Å for 3Co and 4Mg respectively, as calculated by the HT structures. In the same way as we did for $[NH_4][M(HCOO)_3]$,^{23a,b} by these shifts we calculated polarization values of 2.61 and 3.44 μ C cm⁻² for 3Co and 4Mg respectively in their HT phases (Table 2). Therefore, from the above structural information, the phase transitions for the two materials from LT to HT are probably antiferro- to ferroelectric. Since the framework has minor changes during the transition, the N values of 2.7 (3Co) and 2.5 (4Mg) could be considered solely as the results of three discrete states of the trigonally disordered cation in the HT structures vs. one state of ordered cation in the LT phases, with a ratio of N = 3.

The structure investigation revealed that phase transitions occurring in the present materials are all order-disorder like, triggered by the thermally activated motions of the $NH_2NH_3^+$ cation and the accompanied framework modulations. Upon heating, for the perovskites of 1Mn and 2Zn the framework expansion and change are significant, but for the chiral 3Co and 4Mg the framework alterations are small. The significant ATE including NTE for these materials is due to the librational motion of NH₂NH₃⁺ and the conformity and adaptability of the metal-formate frameworks to match such motion. This coupling between the cations and anionic frameworks probably provides a new mechanism for NTE of MOFs, because the guests or cations usually dampen NTE,¹⁷ but this does not seem to be the case for the present AMFFs. We also think that the middle size of $NH_2NH_3^+$ and its characteristics in forming HBs have resulted in such interesting series with two typical AMFF structures.

Dielectric properties and their relevance to structure transitions

The temperature-dependent dielectric permittivity (dielectric constant ε' and loss $\tan \delta$) of the four materials were

investigated. The T_d values of **1Mn** and **4Mg** are *ca.* 50 K and 90 K higher than their T_C values, whereas T_d values for **2Zn** and **3Co** are *ca.* 20 K higher than their T_C values (Table 2). Therefore, the dielectric responses and anomalies of the **1Mn** and **4Mg** corresponding to the phase transitions could be studied with fair reliability, and we focused on these two materials. For **2Zn** and **3Co** the thermal decomposition is quite close to the phase transition, so their dielectric properties are briefly discussed.

The ε' /tan $\delta vs. T$ traces of **1Mn** at 1, 10, 100 and 1000 kHz are shown in Fig. 4a. On heating, the ε' value at 1 MHz increased slowly from 7.0 around 280 K to 10.4 at the turning point of 353 K (Table 2), which is close to the $T_{\rm C}$, then it rose to the quite sharp maximum of 28.0 around 364 K, and went down on further heating, first quickly then slowly, to 14.3 around 390 K. After that the trace showed a small peak around 395 K, then started to rise, and above 410 K it went up more rapidly due to thermal decomposition of the sample. The tan δ data (Fig. 4a, inset) showed the related step around 365 K and the rise around 390 K then the enhancement above 400 K. When the frequency (f) was lowered, the ε' peak values

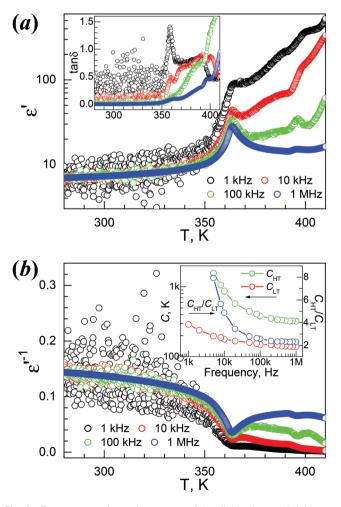


Fig. 4 Temperature-dependent traces of the dielectric permittivities on heating for **1Mn**: (a) ε' vs. *T*, and (inset) tan δ vs. *T*, (b) the relevant $1/\varepsilon'$ vs. *T* plots, and (inset) the plots of C_{LT} . C_{HT} and $C_{\text{HT}}/C_{\text{LT}}$ ratio vs. frequency.

around 364 K increased to 33, 42, 71 and 260 for 100, 10, 1 and 0.1 kHz. The reciprocal permittivity $1/\epsilon'$ vs. T plots (Fig. 4b) showed a V-shape around 364 K, allowing the application of the Curie–Weiss laws $\varepsilon' = C/(T - T_0)$ for the HT side and $\varepsilon' = C/(T_0 - T)$ for the LT side, affording the C/T_0 data in K at 1 MHz, $3.2 \times 10^2/353$ and $1.4 \times 10^2/368$, and the $C_{\rm HT}/C_{\rm LT}$ ratio 2.3. The C values are typical for molecular ferroelectrics undergoing disorder-order transitions of HB systems, 11,12,20 and the T_0 data are close to the $T_{\rm C}$. These data remained nearly unchanged for f values above 100 kHz (Fig. 4b, inset), and the $C_{\rm HT}/C_{\rm LT}$ ratios of 2.3 to 2.6 indicated the possible second order ferro- to para-electric phase transition according to the Devonshire theory.^{20b} Below 100 kHz, the C values and $C_{\rm HT}/C_{\rm LT}$ ratios increased, but the T_0 data changed a little. The prominent dielectric anomaly around 364 K is clearly related to the phase transition at 355 K, triggered by the order-disorder transition of the NH₂NH₃⁺ cation, as discussed before. In the HT para-electric state, the NH₂NH₃⁺ cation has its NH₂ end quickly vibrating between two mirror-related positions. When the temperature is lowered, this librational movement is frozen and the material undergoes a para- to ferro-electric phase transition, leading to the polar LT phase.

4Mg displayed strong frequency dispersion and quite complicated behavior in its dielectric responses and anomalies (Fig. 5, Fig. S10,† Table 2). At 1 MHz, the $\varepsilon' \nu s$. T trace, starting from 7.9 at 280 K, gradually increased to show a first rise step in 335–355 K (ε' = 10–14), then a second rise step from 355 to 375 K ($\varepsilon' = 14-24$), then continuously went up to a maximum of 40.3 around 430 K. After a shallow minimum of 38.6 around 435 K, the trace rose again, probably caused by thermal decomposition (Fig. 5a). The derivative $d\varepsilon'/dT$ plot (Fig. 5a, inset) displayed three maxima at 340, 364 and 415 K, indicating the three increase steps in ε' . The tan δvs . T trace at 1 MHz (Fig. 5b) possesses very similar stepwise characteristics. These data revealed complicated two or three steps phase transitions, as observed in the DSC study. For lower f values, the rise in ε' shifted to lower temperatures, the ε' values increased greatly, and the rise step around 370 K in fact became a broad peak with an ε' value of up to 2.3×10^3 for 100 Hz. Below 1 kHz, the ε' values are high above 370 K. The $1/\varepsilon' \nu s$. T plots (Fig. S10a[†]) are stepwise, and basically include two straight segments in 390-420 K (I) and 350-370 K (II). The data at 1 MHz within these two segments fitted by the Curie–Weiss law $\varepsilon' = C/(T_0 - C_0)$ *T*) resulted in the C/T_0 in K, $3.4 \times 10^3/508$ and $5.4 \times 10^2/393$ for segments I and II, respectively (Table 2). These C values are rational,^{11,12,20} and the T_0 values are higher than T_C . Strong frequency dependence is clearly observed for the $tan\delta$ data shown in Fig. 5b and Fig. S10b.[†] At 100 Hz, a peak in the tan δ vs. T plot was observed at 346 K. With increasing f values, the peak temperatures shifted higher, and became asymmetric by the emergence of two shoulders, a small one on the left and a large one on the right. The right shoulder developed to broad peaks approaching 430 K for f values higher than 2 kHz, and at the same time the original high peaks observed for lower fvalues were gradually suppressed into low shoulders. All these results revealed the relaxor-like behavior of 4Mg,23b,26a,55,56

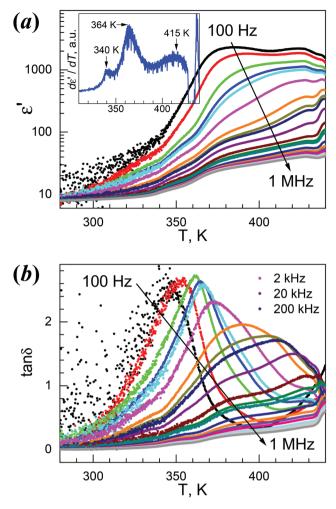


Fig. 5 Temperature-dependent traces of the dielectric permittivities on heating for 4Mg: (a) ε' vs. *T*, and inset $d\varepsilon'/dT$ plot at 1 MHz, (b) tan δ vs. *T*.

and there are seemingly two dielectric relaxation processes, one around 360 K at low f values and the other around 420 K at high f values. In the isothermal $\tan \delta vs.$ f traces from 336 K to 436 K in 4 K spaces (Fig. S10b[†]), the frequency dependence is significant, but the two relaxation processes are not easy to distinguish. However, the log-log plots showed the power law $\tan \delta \sim f^n$ for low and high frequency sides of the peak positions, and typically, for the data of a temperature of 380 K, the exponents were n = 0.65 and -0.41 for both sides. These represent Jonscher's universal relaxation law for dielectrics,⁵⁷ relating to the local transition in the orientation of the $NH_2NH_3^+$ cation and the spread or relaxation in the lattice of the initial transition. The dielectric relaxation observed around 360 K at low f values obeyed the Arrhenius law for the τ = $(2\pi f)^{-1}$ vs. $T_{\rm P}$ (temperature at peak position) data below 2 kHz where $T_{\rm P}$ is located in the ε'' vs. T data, with a pre-exponential factor $\tau_0 = 1.45 \times 10^{-17}$ s and an activation energy $E_{\rm a}/k_{\rm B} = 1.19$ $\times 10^4$ K ~ 1.03 eV (Fig. S10b,† inset). However, the relaxation processes around 420 K and at high f values could not be parameterized because of the broad shoulder or peaks and the temperature very close to $T_{\rm d}$.

The dielectric response of 4Mg could be understood based on the VT structures discussed before. In the LT phase, the cations are completely ordered in the lattice and the LT phase is antiferroelectric, thus the material displayed low dielectric response. On heating, the weak strengths of cation-framework HBs and somewhat large void framework space allow the cation to become trigonally disordered. The HT structure is polar, with all NH_3^+ ends of the cations shifting to the +*c* direction. The polar character and the disorder of the $NH_2NH_3^+$ cation in the HT structure satisfied the requirements for relaxor ferroelectrics,56 therefore resulting in the observed dielectric responses of high ε' values in low f values and strong frequency dispersion. The activation energy for the cation's movement between different orientations is $E_a \sim 1.03$ eV, as revealed by Arrhenius fitting for the frequency dependence around 360 K. This fairly high activation energy might be related to the antiferro- to ferroelectric phase transition and the observed two or three steps involved. VT structures with fine temperature intervals will be of help to reveal the details. 4Mg might experience another phase transition above 420 K because of the observation of the peaks in both $\varepsilon'' vs. T$ and $\tan \delta$ vs. T traces, and this might be ferro- to para-electric, though no further information could be obtained due to sample decomposition.

2Zn and **3Co** showed the relevant dielectric anomaly shoulders around their $T_{\rm C}$ values, as shown in Fig. S11† (**2Zn**) and Fig. S12† (**3Co**). Since their $T_{\rm C}$ values are close to the $T_{\rm d}$ values, the dielectric anomalies were superimposed by the further enhanced dielectric responses due to the decomposition subsequently occurred. However, some information could still be retrieved from the data below $T_{\rm C}$, *e.g.* the rational C/T_0 values in K, $3.3 \times 10^2/372$ and $3.3 \times 10^2/405$ at 1 MHz, for **2Zn** and **3Co** respectively. These data are listed in Table 2.

Therefore, the dielectric responses and phase transitions of the four present AMFF materials are clearly related to the order-disorder transition of the NH₂NH₃⁺ cations within the structures, and their basic relevance has been established. The very prominent dielectric anomalies indicate that the LT phases of **1Mn** and **2Zn**, and the HT phases of **3Co** and **4Mg**, being all polar, are probably ferroelectric, though further experimental investigation such as electric hysteresis measurements will be needed when large crystals are available.

Magnetic properties of 1Mn and 3Co

The temperature evolutions of the direct current (dc) susceptibilities of **1Mn** and **3Co** (plots of $\chi T \nu s. T$, Fig. 6a) indicate that the two materials mainly displayed spin-canted AF characters. The χT values at 300 K, 4.39 (**1Mn**) and 3.19 (**3Co**) cm³ K mol⁻¹, are expected for the two divalent octahedral metal ions.⁵⁸ On cooling from 300 K to *ca.* 50 K the χT values decreased slowly. Below 50 K the values of χT decreased quickly to reach the minima, then rose to the maxima and then fell again upon further cooling (Table 4). This suggested the occurrence of spontaneous magnetization or magnetic LRO within the materials. The rise for **3Co** was much steeper, with a high maximum of 45.4 cm³ K mol⁻¹, similar to

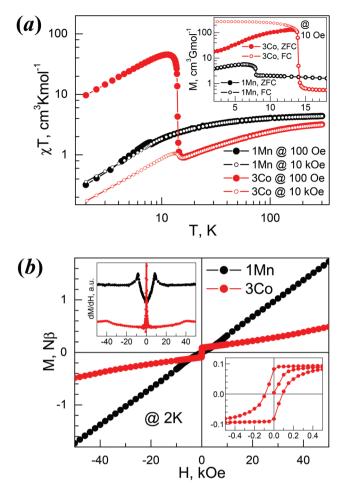


Fig. 6 Magnetism of 1Mn and 3Co. (a) Plots of $\chi T vs. T$ under 100 Oe and 10 kOe fields, (inset) the ZFC/FC plots of the 1Mn and 3Co under 10 Oe field. (b) Isothermal magnetization plots of 1Mn and 3Co at 2 K, (top-left inset) the dM/dH plots, (bottom-right inset) hysteresis loop for 3Co.

[HONH₃][Co(HCOO)₃].³³ The high temperature susceptibility data obey the Curie–Weiss law well (Fig. S13a[†]) with Curie constants (*C*) and Weiss temperatures (Θ) in cm³ K mol⁻¹ and K respectively: 4.57/–13.2 (**1Mn**), 3.80/–56.8 (**3Co**). The Landé *g*-factors derived from the *C* values are 2.04 (**1Mn**) and 2.58 (**3Co**), typical for isotropic Mn²⁺ and anisotropic Co^{2+,58} These data are comparable to related metal members in other AMFF series,²¹ and the significant negative Θ values indicate AF exchange interactions between metal ions, *via anti–anti* formato bridges. Under an applied field of 10 kOe, in high temperature regions the χT traces were almost identical to the traces under a 100 Oe field, while in low temperature regions the rises after the minima were suppressed for **1Mn**, but still observed for **3Co**. These observations characterized the two materials as weak ferromagnets.

The magnetism in the low temperature region for **1Mn** and **3Co** were further investigated by zero-field and field cooled measurements (ZFC/FC, Fig. 6a, inset), isothermal magnetizations (Fig. 6b), and ac susceptibility measurements (Fig. S13b†). The bifurcations in ZFC/FC traces, though not very significant for **1Mn**, indicated the 3D spin-canted AF LRO

Table 4 Summary of magnetic properties of **1Mn** and **3Co**, Curie constants, Weiss constants, listed χT values, and g factors were upon susceptibility data under 100 Oe field, and 10 kOe data in parentheses

Compound	1Mn	3Co
$C^a/\mathrm{cm}^3 \mathrm{K} \mathrm{mol}^{-1}$	4.57 (4.53)	3.80 (3.73)
Θ^b/K	-13.2(-12.8)	-56.8(-55.8)
$(\chi T)_{300 \text{ K}}/\text{cm}^3 \text{ K mol}^{-1}$	4.39 (4.36)	3.19 (3.19)
$(\chi T)_{\min}$ ^c /cm ³ K mol ⁻¹ , T_{\min}/K	1.50, 8.0	0.90, 15.5
$(\chi T)_{\rm max}^{c}/{\rm cm}^3 {\rm K}{\rm mol}^{-1}, T_{\rm max}/{\rm K}$	1.61, 7.8	45.4, 11.5
$(\chi T)_{2 \text{ K}}/\text{cm}^3 \text{ K mol}^{-1}$ T_N^{-d}/K	0.32 (0.36)	9.70 (1.88)
$T_{\rm N}^{d}/{\rm K}$	7.9	13.9
$T_{\rm p}^{\ \ e}/{\rm K}$	8.0	13.8-13.9
1.		13.5-13.8
$H_{\rm C}^{f}$ /kOe (at 2 K)	< 0.01	0.09
$M_{\rm R}^{g}/N\beta$ (at 2 K)	< 0.001	0.082
$M_{50 \text{ kOe}}/N\beta$ (at 2 K)	1.73	0.49
$\alpha^{h/\circ}$	< 0.001	1.10
$H_{\rm SP}^{i}$ /kOe (at 2 K)	8.50	>40
$J^{j}/k_{\rm B}$ (K)	-0.38	-3.8
g ^k Factor	2.04 (2.04)	2.85 (2.82)

^{*a*} Curie constants. ^{*b*} Weiss constants. ^{*c*} Minimum and maximum χT values and the related temperatures. ^{*d*} Critical temperatures based on ZFC/FC measurements. ^{*e*} Temperatures at peak positions in ac measurements at zero dc field, the first line for in-phase ac response and the second line for out-of-phase response. ^{*f*} Coercive fields. ^{*g*} Remnant magnetizations. ^{*h*} Canting angles, see text. ^{*i*} Fields for spin flop from peak or first turn positions in dM/dH. ^{*j*} Estimated from $J/k_{\rm B} = 3\Theta/[2zS(S+1)]$. ^{*k*} *g* Factors derived from Curie constants.

for the two materials at Néel temperatures (T_N) of 7.9 K and 13.9 K for 1Mn and 3Co, respectively, determined by the negative peak positions on the dFC/dT data (not given here). For 1Mn, the spontaneous magnetization was less than 6 cm³ G mol⁻¹, while 3Co showed a large spontaneous magnetization of *ca.* 250 cm³ G mol⁻¹, in agreement with the large χT values at low temperatures. Known AMFFs with large spontaneous magnetizations include 3Co, chiral [HONH₃][Co(HCOO)₃],³³ [C(NH₂)₃][Co(HCOO)₃]^{29a} perovskite and niccolite [CH₃NH₂CH₂CH₂NH₂CH₃][Fe₂(HCOO)₆].³⁴ At 2.0 K (Fig. 6b), 1Mn showed nearly no hysteresis (remnant magnetization $M_{\rm R} < 0.001 N\beta$ and $H_{\rm C} < 10$ Oe) but small kinks around 8 kOe (Fig. 6b, top-left inset). In higher fields the magnetization increases linearly and reaches *ca.* $1.7N\beta$ at 50 kOe, being one third of the saturation value of $5N\beta$ for Mn^{2+} (S = 5/2 and g = 2.00). For 3Co (Fig. 6b, bottom-right inset), a hysteresis was observed, with $M_{\rm R}$ and $H_{\rm C}$ being $0.082N\beta$ and 90 Oe. In the high field region the magnetizations showed a slow increase with a slight turning up around 40 kOe, and the magnetizations were $0.49N\beta$ at 50 kOe. Spin-flop transitions (AF-SP)⁵⁹ occurred at 2 K for 1Mn and 3Co, and the fields for spin-flop (H_{SP}) , estimated by peak position of dM/dH, were 8.5 kOe for 1Mn and 40 kOe for 3Co. From the $M_{\rm R}$ values the canting angle could be estimated at less than 0.001° for 1Mn and 1.1° for 3Co, respectively,⁵⁹ assuming the existence of two AF interacted sub-lattices in the materials. In ac susceptibilities (Fig. S13b⁺), 1Mn displayed frequency-independent peaks in its in-phase (χ') responses at 8.0 K, close to the $T_{\rm N}$ = 7.9 K by dc measurement, while the out-of-phase (χ'') responses were in the noise level. 3Co showed slight

frequency-dependent χ' and χ'' peaks around 13.8 K, with a small $\phi = (\Delta T_{\rm P}/T_{\rm P})/\Delta (\log f)^{60} \sim 0.004$, where $T_{\rm P}$ is the peak temperature of χ' and f the ac frequency. This relaxation behaviour, similar to that encountered for some Co-AMFFs,^{29*a*,33} could be due to domain-wall movement,⁶¹ or chirality-related ac responses⁶² as **3Co** is chiral. The M…M magnetic couplings through the *anti–anti* formato bridge within the two solids could be estimated by using the molecular field result, $J/k_{\rm B} = 3\Theta/[2zS(S + 1)]$, and were -0.38 (**1Mn**) and -3.8 K (**3Co**) for z = 6 and S = 5/2 and 3/2 for **1Mn** and **3Co**, respectively, and they are comparable to those found in AMFFs.²¹ The spin-canted AF is due to the occurrence of Dzyaloshinsky–Moriya or the antisymmetric interaction⁶³ resulting from the non-centrosymmetric bridges of *anti–anti* HCOO linking magnetic sites, as observed for many AMFFs.²¹

Finally, we emphasize that **1Mn** and **3Co** showed both electric and magnetic LRO in low temperature regions, and this makes the magnetic members of the present series of great interest for the research on MOF/molecule-based multiferroics which were only recognized very recently,^{9,23,26,29,30} and probably adds a new family of AMFF multiferroic materials.

Conclusion

In conclusion, we have successfully synthesized and characterized a new class of AMFFs of [NH₂NH₃][M(HCOO)₃] (M = divalent Mn, Zn, Co and Mg) by employing hydrazinium as the cationic template and component. The series has two typical AMFF structures. The Mn and Zn members are perovskites, with anionic 4¹²·6³ metal-formate frameworks and the cubic cavities occupied by the NH₂NH₃⁺ cations. They undergo structural transitions around 350 K, in which the structures change from LT polar phases in Pna21 to HT non-polar phases in Pnma, due to the occurrence of the librational movement of the NH₂ end of the NH₂NH₃⁺ cation in the cavity and related significant framework regulation and expansion. The Co and Mg members possess chiral 49.66 metal-formate frameworks with chiral hexagonal channels accommodating NH₂NH₃⁺ cations. The LT phases in non-polar P212121 are probably antiferroelectric. They display phase transitions at 380 K (Co) and 348 K (Mg) and change to a polar HT phase in $P6_3$ because of the occurrence of trigonal disorder in the cation. Accompanied by these transitions the materials show prominent anisotropic/ negative thermal expansion and dielectric anomalies, and their structural relevance is established. From LT to HT, the phase transitions of Mn and Zn members are ferro- to paraelectric, while for the Co and Mg members the transitions are probably antiferro- to ferro-electric. The spontaneous polarization for the polar structures was estimated at 3.58 (Mn, 110 K), 3.48 (Zn, 110 K), 2.61 (Co, 405 K) and 3.44 (Mg, 400 K) μ C cm⁻². The two magnetic Mn and Co members also show long-range-ordering of spin-canted antiferromagnetism, with Néel temperatures of 7.9 K and 13.9 K, respectively. Therefore, they constitute new molecule-based multiferroics. It is also expected that the present series will produce more than ten

new AMFFs showing interesting phase transitions occurring at high temperatures even comparable to the ferroelectric oxides, and the relevant NTE, electric, magnetic and possible multiferroic properties if the two polymorphs for all divalent metal ions from Mn to Zn plus Mg were obtained. The series will probably become a new prototypical class of MOF-based multiferroics, and much further research is required. This research is in progress.

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